

V_{DSS} , 30V $R_{DS(ON)}$, 3.5m Ω (max.) @ $V_{GS}=10V$ $R_{DS(ON)}$, 4.9m Ω (max.) @ $V_{GS}=4.5V$ I_D , 100A	PDFN 5x6-8L		

Description	Features
The SG30N06Q uses advanced Trench technology and designs to provide excellent $R_{DS(ON)}$ with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.	<ul style="list-style-type: none"> Low On-Resistance Low Input Capacitance Low Miller Charge Low Input / Output Leakage Pb-free lead plating; RoHS compliant
	Applications
	<ul style="list-style-type: none"> Motor / Body Load Control Load Switch DC-DC converters and Off-line UPS

Ordering Information

Ordering Code	RoHS Status	Package	Package Code	Packing	Quantity
SG30N06Q	Halogen-Free	PDFN 5x6-8L	Q	Tape & Reel	2,500

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	$T_C=25^\circ\text{C}$	100
		$T_C=100^\circ\text{C}$	82
Drain Current-Pulsed ^{Note 1}	I_{DM}	350	A
Drain Current-Continuous	I_D	$T_A=25^\circ\text{C}$	20
		$T_A=70^\circ\text{C}$	16
Avalanche Current	I_{AS}	50	A
Avalanche Energy, $L=0.1\text{mH}$	E_{AS}	125	mJ
Maximum Power Dissipation	P_D	$T_C=25^\circ\text{C}$	71.4
		$T_C=100^\circ\text{C}$	35.7
		$T_A=25^\circ\text{C}$	2
		$T_A=70^\circ\text{C}$	0.8
Operating Junction Temperature Range	T_J T_{STG}	-55 to +175	$^\circ\text{C}$

Thermal Resistance Ratings

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Maximum Junction-to-Ambient	$R_{\theta JA}$	Steady State	-	-	62	$^\circ\text{C/W}$
Maximum Junction-to-Case	$R_{\theta JC}$	Steady State	-	-	1.7	$^\circ\text{C/W}$

Electrical Characteristics (T_J=25°C unless otherwise noted)

OFF CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _{DS} =250μA	30	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =24V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA

ON CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Gate Threshold Voltage	V _{GS(TH)}	V _{DS} =V _{GS} , I _{DS} =250μA	1.2	-	2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _{DS} =30A	-	-	3.5	mΩ
Drain-Source On-State Resistance		V _{GS} =4.5V, I _{DS} =12A	-	-	4.9	

DYNAMIC CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHz	-	2156	-	pF
Output Capacitance	C _{oss}		-	274	-	
Reverse Transfer Capacitance	C _{rss}		-	173	-	
Gate Resistance	R _g	V _{GS} =0V, V _{DS} =0V, f=1MHz	-	1	-	Ω

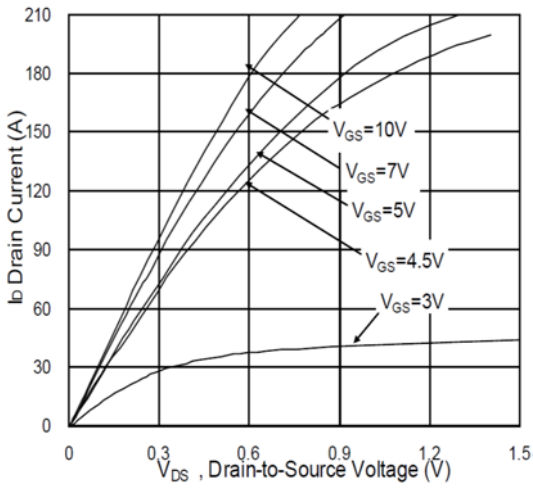
SWITCHING CHARACTERISTICS						
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Turn-On Delay Time	T _{d(on)}	V _{DD} =15V, I _D =12A, V _{GS} =10V, R _g =3.3Ω	-	12.3	-	ns
Rise Time	t _r		-	19.1	-	
Turn-Off Delay Time	T _{d(off)}		-	41.9	-	
Fall Time	t _f		-	12.9	-	
Total Gate Charge	Q _g	V _{DS} =15V, I _{DS} =24A, V _{GS} =4.5V	-	31	-	nC
Gate to Source Gate Charge	Q _{gs}		-	8.4	-	
Gate to Drain "Miller" Charge	Q _{gd}		-	11.4	-	

DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Maximum Body-Diode Continuous Current	I _S	V _G =V _D =0V, Force Current	-	-	100	A
Pulsed Source Current	I _{SM}	V _G =V _D =0V, Force Current	-	-	350	A
Drain-Source Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =1A	-	0.8	1.2	V

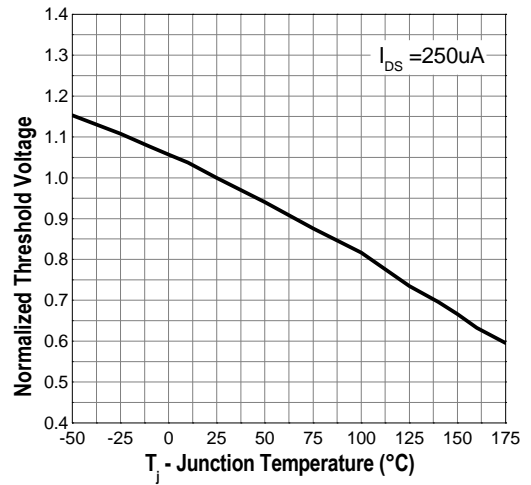
- Notes:**
- Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
 - R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θJA} is determined by the user's board design. R_{θJA} shown below for single device operation on FR-4 in still air.

Typical Operating Characteristics

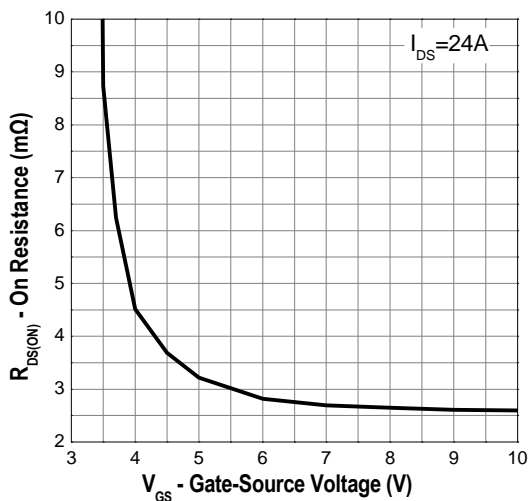
Output Characteristics



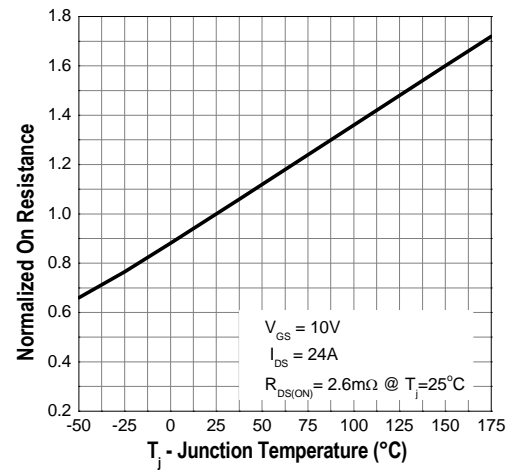
Gate Threshold Voltage



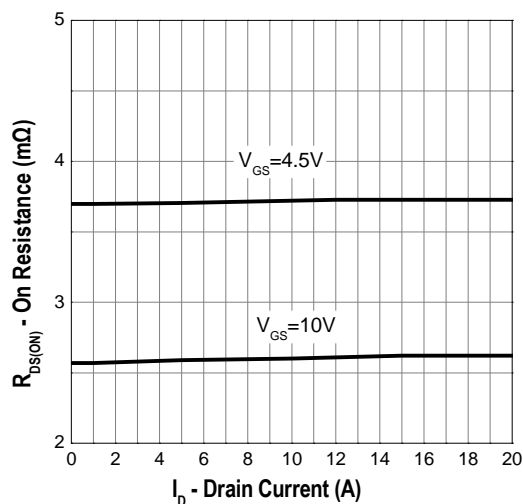
Gate-Source On Resistance



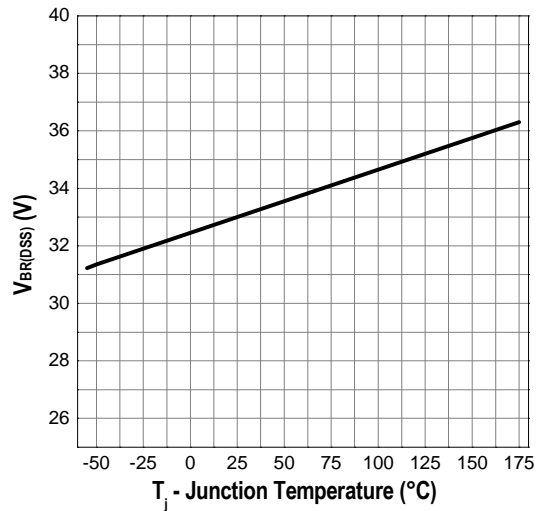
Drain-Source On Resistance



Drain-Source On Resistance

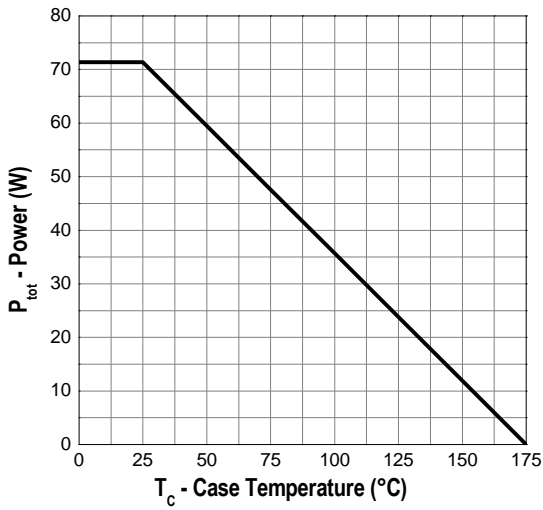


Drain-source Breakdown Voltage

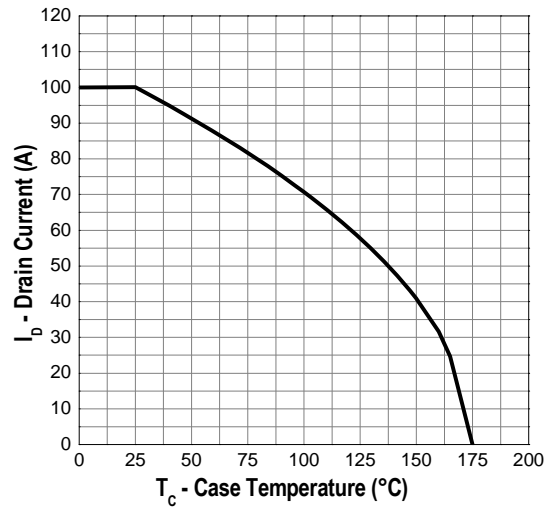


Typical Operating Characteristics (Cont.)

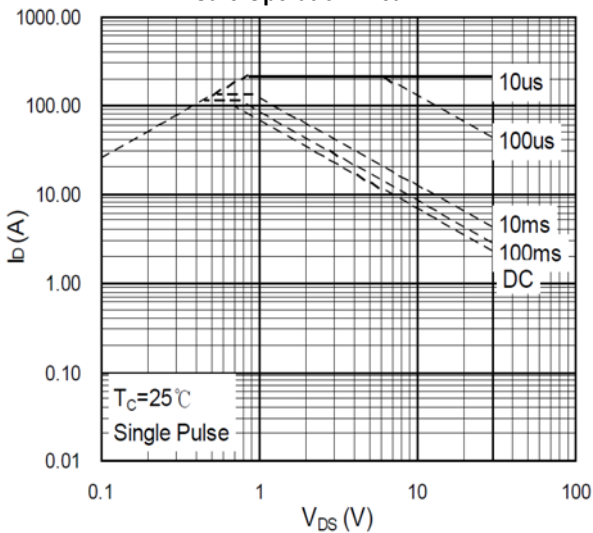
Power Dissipation



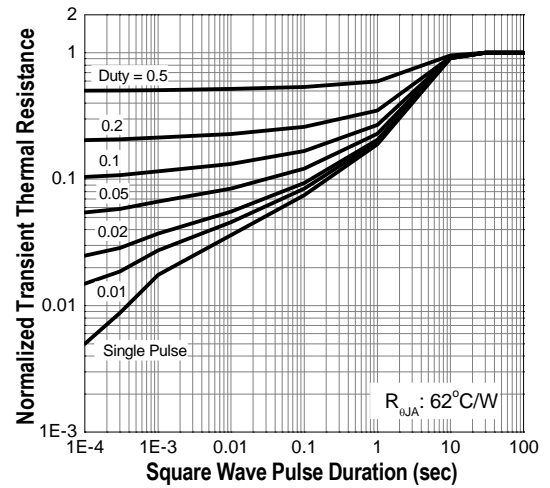
Drain Current



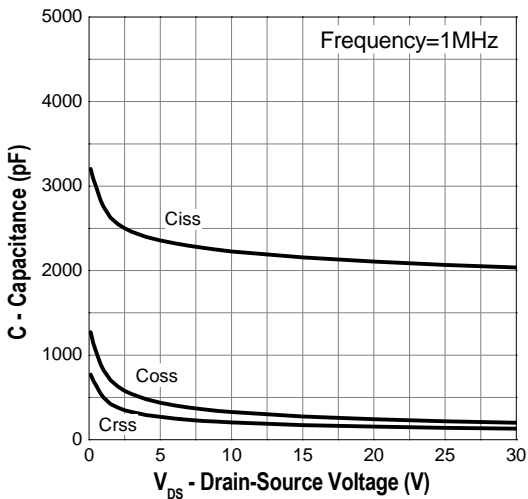
Safe Operation Area



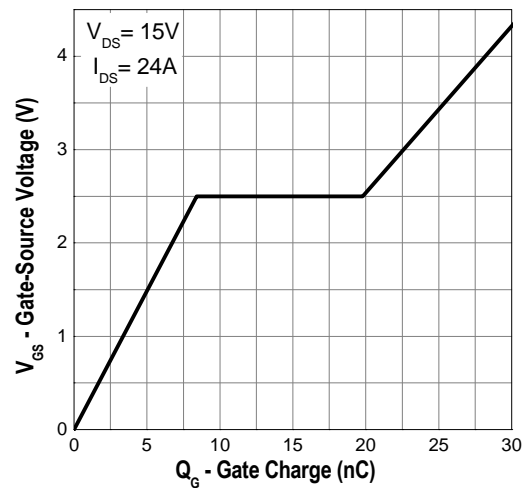
Transient Thermal Impedance




Capacitance



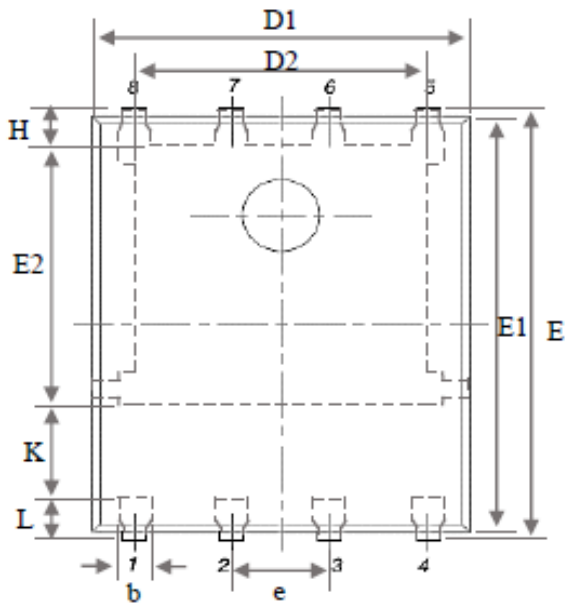
Gate Charge



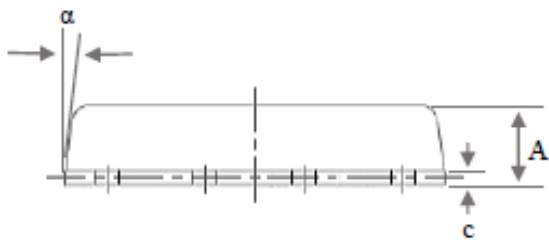
Marking Information

PDFN 5x6-8L (Q)	Marking Rule
<p>Laser Marking</p> 	<p><u>Line 1</u> : Device Name SG30N06Q</p> <p><u>Line 2</u> : Date Code YYMMXXX</p> <p>YY : Year Code MM : Month Code XXX : Serial Number</p>

Package of Dimension



Symbol	Min	Nor	Max
A	0.90	1.04	1.17
b	0.33	0.42	0.51
C	0.06	0.20	0.35
D1	4.80	5.10	5.40
D2	3.61	3.96	4.31
E	5.90	6.03	6.15
E1	5.65	5.75	5.85
E2	3.30	3.54	3.78
e	1.27 BSC		
H	0.38	0.50	0.61
L	0.38	0.55	0.71
L1	0.05	0.15	0.25

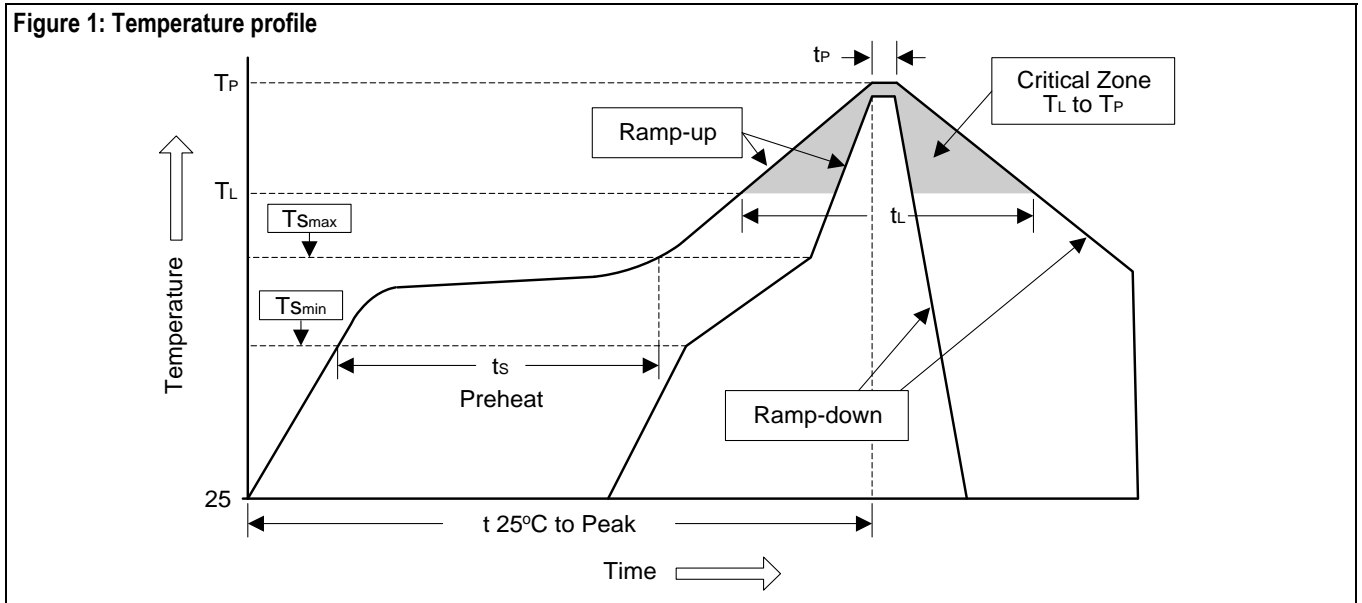


1. All dimension are in millimeters.
2. Dimension does not include burrs and mold flash/protrusions.

Soldering Methods for Silicongear's Products

1. Storage environment: Temperature=10°C to 35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices

Figure 1: Temperature profile



Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average ramp-up rate (T_L to T_P)	<3°C/sec	<3°C/sec
Preheat		
- Temperature Min (T_{Smin})	100°C	150°C
- Temperature Max (T_{Smax})	150°C	200°C
- Time (min to max) (t_s)	60 to 120 sec	60 to 180 sec
T_{Smax} to T_L		
- Ramp-up Rate	<3°C/sec	<3°C/sec
Time maintained above:		
- Temperature (T_L)	183°C	217°C
- Time (t_L)	60 to 150 sec	60 to 150 sec
Peak Temperature (T_P)	240°C +0/-5°C	260°C +0/-5°C
Time within 5°C of actual Peak Temperature (t_P)	10 to 30 sec	20 to 40 sec
Ramp-down Rate	<6°C/sec	<6°C/sec
Time 25°C to Peak Temperature	<6 minutes	<8 minutes

3. Flow (wave) soldering (solder dipping)

Products	Peak Temperature	Dipping Time
Pb devices.	245°C ±5°C	5sec ±1sec
Pb-Free devices.	260°C +0/-5°C	5sec ±1sec

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